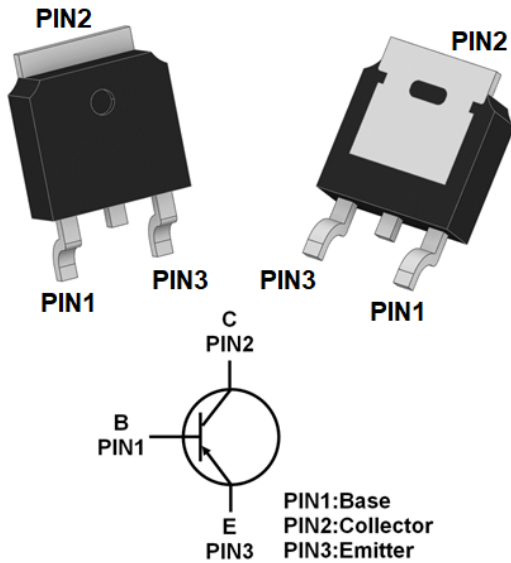


PNP High Power Bipolar Transistor



Features

- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Complement to MJD122
- High DC Current Gain

Mechanical Data

- Package: TO-252
- Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Unit Weight: 0.32g

■ Maximum Ratings (Ta=25°C unless otherwise noted)

Item	Symbol	Unit	Value
Device marking code			MJD127
Collector-base voltage	V_{CBO}	V	-100
Collector-emitter voltage	V_{CEO}	V	-100
Emitter-base voltage	V_{EBO}	V	-5
Collector current	I_C	A	-5
Power dissipation(Note1)	P_D	W	1.5
Thermal resistance, junction-to-ambient (°)	R_{thJA}	°C/W	83.3
Junction temperature	T_j	°C	-55 to +150
Storage temperature	T_{STG}	°C	-55 to +150

Note1: The data tested by surface mounted on a 40*40*1.1mm heatsink.

MJD127

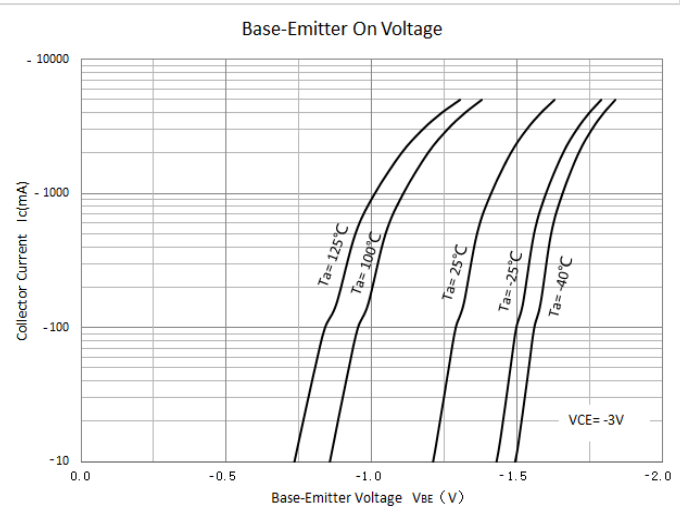
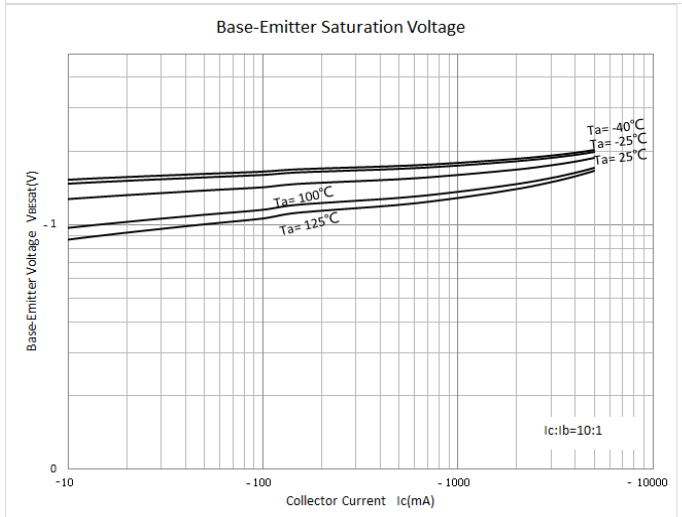
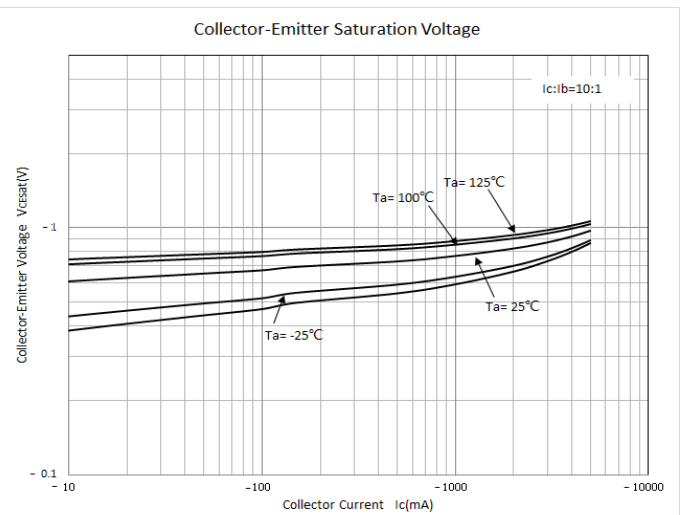
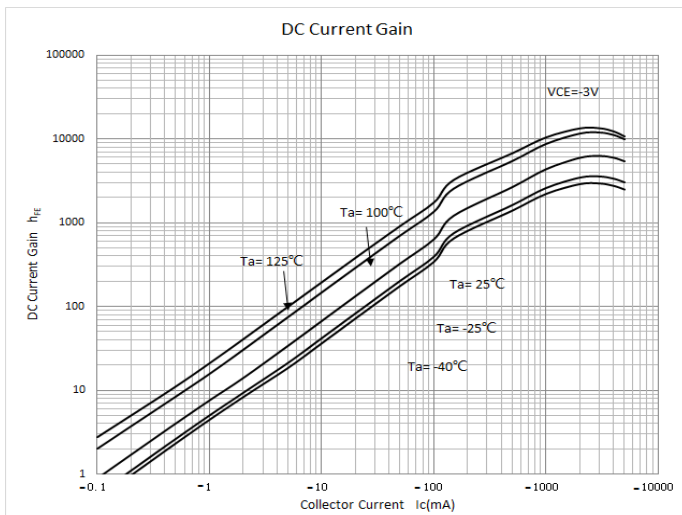
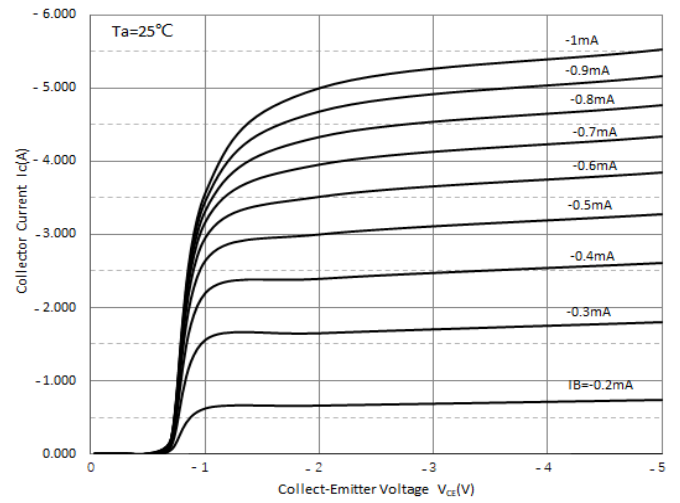
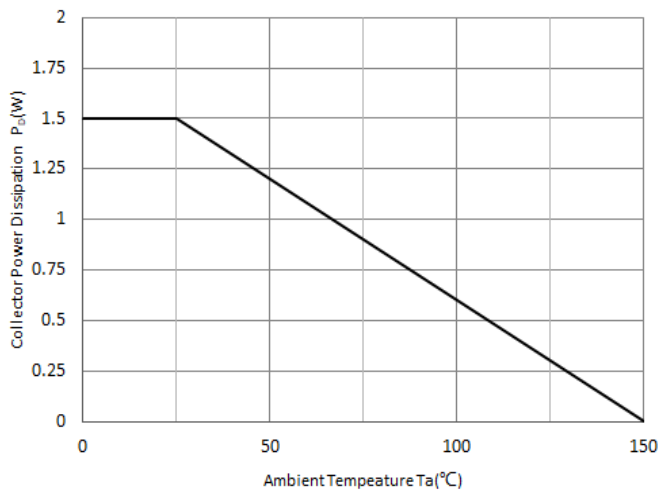
■ Electrical Characteristics (Ta=25°C unless otherwise noted)

Item	Symbol	Unit	Conditions	Min	Typ	Max
Collector-base breakdown voltage	$V_{(BR)CBO}$	V	$I_C=-1mA, I_E=0$	-100		
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	V	$I_C=-30mA, I_B=0$	-100		
Emitter-base breakdown voltage	$V_{(BR)EBO}$	V	$I_E=-2mA, I_C=0$	-5		
Collector-base cut-off current	I_{CBO}	mA	$V_{CB}=-100V$			-0.2
Collector cutoff current	I_{CEO}	mA	$V_{CE}=-30V$			-0.5
Emitter-base cut-off current	I_{EBO}	mA	$V_{EB}=-5V$			-2
DC current gain	h_{FE}		$V_{CE}=-3V, I_C=-0.5A$	1000		
			$V_{CE}=-3V, I_C=-3A$	1000		
Collector-emitter saturation voltage	$V_{CE(sat)}$	V	$I_C=-3A, I_B=-12mA$			-2.0
			$I_C=-5A, I_B=-20mA$			-4.0
Base-Emitter Voltage	V_{BE}	V	$V_{CE}=-3V, I_C=-3A$			-2.5
Collector-base output capacitance	Cob	pF	$V_{CB}=-10V, I_E=0A, f=1MHz$		88	

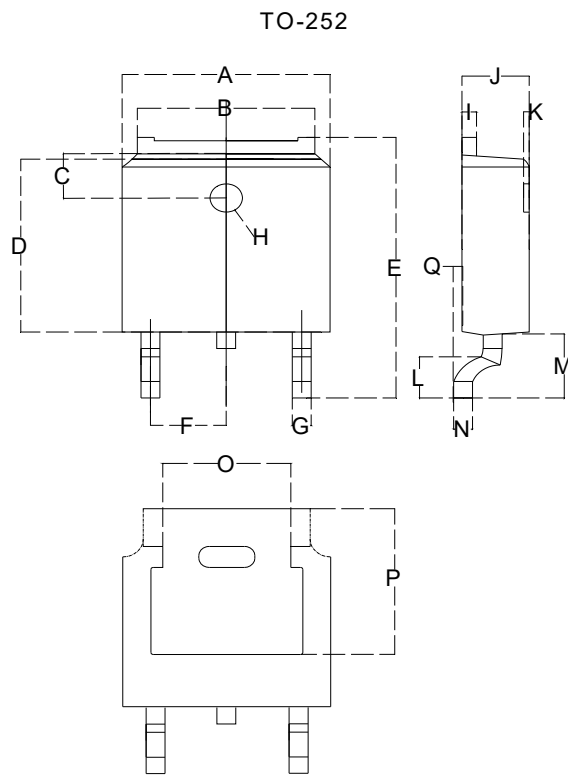
■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MJD127	F2	2500	5000	25000	13"Reel

■ Characteristics(Typical)



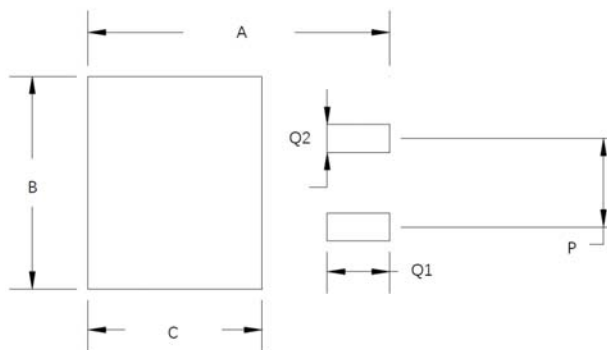
■ **TO-252 Package information**



Dimensions in millimeters

TO-252		
Dim	Min	Max
A	6.500	6.700
B	5.100	5.460
C	1.400	1.800
D	6.000	6.200
E	10.000	10.400
F	2.166	2.366
G	0.660	0.860
H	Φ 1.050	Φ 1.350
I	0.460	0.580
J	2.200	2.400
K	0	0.300
L	0.890	2.290
M	2.730	3.080
N	0.430	0.580
O	4.20	4.95
P	5.15	5.45
Q	0	0.2

■ **Suggested Pad Layout**



Dim	Millimeters
A	11.4
B	6.74
C	6.23
P	4.56
Q1	2.28
Q2	1.52

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